



Plasmonic Modulators for THz Wireless Signal Processing

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The THz frequency range is rapidly gaining attention in a number of key application domains, including security screening, sensing, medical imaging and, not least, next-generation wireless communications. Particularly evident is the exponential growth of wireless data traffic, with capacity demands reaching tens to hundreds of Gb/s [1]. Those speeds require large transmission bandwidths, but the currently used microwave bands have a limited allocated spectrum, typically limited to a few hundred MHz. Millimeter-wave spectrum in the V- and E-bands offer larger available spectral resources, yet contiguous bandwidths are still below 9 GHz. This renders wireless data rates of hundreds of Gb/s, while keeping hundreds meter link lengths, difficult to realize. The THz band (300 GHz – 10 THz) is thus seen as the “next frontier” for future data links thanks to the extremely large bandwidths available [2]. Accessing the THz spectrum, however, poses several challenges compared to microwaves, namely sensitivity to blockage, largely increased free-space path loss, and atmospheric absorption due to water vapor [1]. In addition, the generation of THz signals with sufficient power as well as their detection are not trivial tasks. Approaches use either electronic [3] or photonic techniques [2, 4, 5], the latter being particularly attractive as they offer seamless integration with the existing fiber networks [6, 7]. For optical-to-THz conversion, uni-travelling carrier photodiodes (UTC-PD) are a well-proven solution [2]. THz-to-optical conversion, in turn, demands very fast electro-optic modulators, with electro-optic bandwidth well above 300 GHz, high power handling and high linearity [8]. Impressive progress has been reported in lithium niobate modulators [9, 10], reaching losses as low as 0.5 dB and an RF half-wave voltage as little as 1.4 V [11]. We recently showed plasmonic Mach-Zehnder modulators displaying the desired characteristics of speed, linearity and power handling simultaneously [12], with a flat frequency response up to 500 GHz, a third-order input intercept point (IIP3) of 18.9 dBm and stable operation at high electrical power level up to 24.4 dBm. We will present their characterization and the implementation of a microwave photonic link at 325 GHz, with >100 GHz bandwidth, only limited by our electrical measurement equipment.

References

1. A. J. Seeds, H. Shams, M. J. Fice, and C. C. Renaud, "TeraHertz Photonics for Wireless Communications," *Lightwave Technology, Journal of* **33**, 579 (2015).
2. S. Jia, X. Pang, O. Ozolins, *et al.*, "0.4 THz Photonic-Wireless Link With 106 Gb/s Single Channel Bitrate," *Journal of Lightwave Technology* **36**, 610 (2018).
3. "Virginia Diodes, Extension Modules," <https://www.vadiodes.com/en/products/signal-generator>.
4. Y. Salamin, P. Ma, B. Baeuerle, *et al.*, "100 GHz Plasmonic Photodetector," *ACS Phot.* **5**, 3291 (2018).
5. Y. Salamin, I.-C. Benea-Chelmus, Y. Fedoryshyn, *et al.*, "Compact and ultra-efficient broadband plasmonic terahertz field detector," *Nat. Commun.* **10**, 5550 (2019).
6. T. Nagatsuma, S. Horiguchi, Y. Minamikata, *et al.*, "Terahertz wireless communications based on photonics technologies," *Opt. Express* **21**, 23736 (2013).
7. Y. Salamin, B. Baeuerle, W. Heni, *et al.*, "Microwave plasmonic mixer in a transparent fibre-wireless link," *Nature Photonics* **12**, 749 (2018).
9. P. O. Weigel, J. Zhao, K. Fang, *et al.*, "Bonded thin film lithium niobate modulator on a silicon photonics platform exceeding 100 GHz 3-dB electrical modulation bandwidth," *Opt. Express* **26**, 23728 (2018).
10. A. J. Mercante, S. Shi, P. Yao, *et al.*, "Thin film lithium niobate electro-optic modulator with terahertz operating bandwidth," *Opt. Express* **26**, 14810 (2018).
11. C. Wang, M. Zhang, X. Chen, *et al.*, "Integrated lithium niobate electro-optic modulators operating at CMOS-compatible voltages," *Nature* **562**, 101 (2018).
12. M. Burla, C. Hoessbacher, W. Heni, *et al.*, "500 GHz plasmonic Mach-Zehnder modulator enabling sub-THz microwave photonics," *APL Photonics* **4**, 1 (2019).